

Data Sheet Issue:- 2

# Rectifier Diode Types W6262Z#200 to W6262Z#240 Previous Type No.: SW20-24#XC2850

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V <sub>RRM</sub>	Repetitive peak reverse voltage, (note 1)	2000-2400	V
Vrsm	Non-repetitive peak reverse voltage, (note 1)	2100-2500	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
IF(AV)M	Maximum average forward current, Tsink=55°C, (note 2)	6262	А
IF(AV)M	Maximum average forward current. T <sub>sink</sub> =100°C, (note 2)	4616	А
IF(RMS)M	Nominal RMS forward current, T <sub>sink</sub> =25°C, (note 2)	11327	А
I <sub>F(d.c.)</sub>	D.C. forward current, T <sub>sink</sub> =25°C, (note 3)	9885	А
IFSM	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> =60%V <sub>RRM</sub> , (note 4)	67	kA
IFSM2	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 4)	73.7	kA
l²t	$I^{2}t$ capacity for fusing $t_{p}$ =10ms, $V_{rm}$ =60% $V_{RRM}$ , (note 4)	22.4×10 <sup>6</sup>	A <sup>2</sup> s
l²t	$I^{2}t$ capacity for fusing $t_{p}$ =10ms, $V_{rm}$ ≤10V, (note 4)	27.2×10 <sup>6</sup>	A <sup>2</sup> s
T <sub>j op</sub>	Operating temperature range	-40 to +175	°C
T <sub>stg</sub>	Storage temperature range	-55 to +175	°C

Notes:-

1) De-rating factor of 0.13% per °C is applicable for  $T_j$  below 25°C.

2) Double side cooled, single phase; 50Hz, 180° half-sinewave.

3) Double side cooled.

4) Half-sinewave, 175°C T<sub>j</sub> initial.



## **Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
Vfm	Maximum peak forward voltage	-	-	1.18	IFM=6800A	V
V <sub>T0</sub>	Threshold voltage	-	-	0.73		V
r⊤	Slope resistance	-	-	0.064		mΩ
I <sub>RRM</sub>	Peak reverse current	-	-	150	Rated V <sub>RRM</sub>	mA
D	Thermal registeres, junction to besteink	-	-	0.011	Double side cooled	K/W
RthJK	Thermal resistance, junction to heatsink	-	-	0.022	Single side cooled	K/W
F	Mounting force	27	-	47	Note 2	kN
Wt	Weight		1.7			kg

Notes:-

1) Unless otherwise indicated  $T_j=175^{\circ}C$ .

2) For other clamp forces, please consult factory.



 $W_{AV} = \frac{\Delta T}{R_{th}}$  $\Delta T = T_{j \max} - T_{K}$ 

#### Notes on Ratings and Characteristics

#### 1.0 Voltage Grade Table

Voltage Grade	V <sub>RRM</sub> V	V <sub>RSM</sub> V	V <sub>R</sub> DC V
20	2000	2100	1250
24	2400	2500	1450

#### 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

#### 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T<sub>j</sub> below 25°C.

#### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

and:

#### 5.0 Computer Modelling Parameters

#### 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{2} + 4 \cdot ff^{2} \cdot r_{T} \cdot W_{AV}}}{2 \cdot ff^{2} \cdot r_{T}}$$

Where V<sub>τ0</sub>=0.73V, r<sub>τ</sub>=0.064mΩ,

 $R_{th}$  = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance						
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.		
Square wave Double Side Cooled	0.0144	0.0132	0.0126	0.0116		
Square wave Cathode Side Cooled	0.0262	0.0251	0.0244	0.0235		
Sine wave Double Side Cooled	0.0133	0.0124	0.0115			
Sine wave Cathode Side Cooled	0.0253	0.0244	0.0234			

Form Factors						
Conduction Angle6 phase (60°)3 phase (120°)½ wave (180°)d.c.						
Square wave	2.449	1.732	1.414	1		
Sine wave	2.778	1.879	1.57			



#### 5.2 Calculating VF using ABCD Coefficients

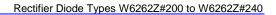
The forward characteristic I<sub>F</sub> vs. V<sub>F</sub>, on page 6 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V<sub>F</sub> in terms of I<sub>F</sub> given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	175°C Coefficients
А	0.72773586	0.527673862
В	-4.783379×10 <sup>-4</sup>	2.842161×10 <sup>-3</sup>
С	1.888101×10 <sup>-5</sup>	3.968936×10⁻⁵
D	3.638078×10 <sup>-3</sup>	4.131844×10 <sup>-3</sup>





5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to *n*, *n* is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- $r_t =$  Thermal resistance at time t.
- $r_p$  = Amplitude of  $p_{th}$  term.
- $\tau_p$  = Time Constant of r<sub>th</sub> term.

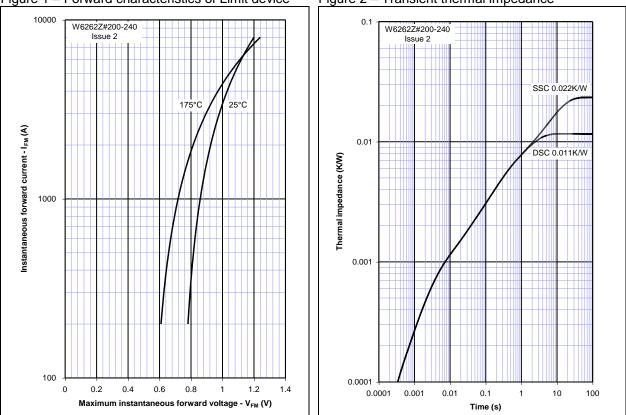
The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled								
Term	Term 1 2 3 4							
r <sub>p</sub>	0.01551	2.7827×10 <sup>-3</sup>	4.2105×10 <sup>-3</sup>	0.9443×10 <sup>-3</sup>				
τρ	10.04275	1.783567	0.2231307	3.428×10⁻³				

D.C. Double Side Cooled							
Term	Term 1 2 3 4 5						
rp	6.4176×10 <sup>-3</sup>	2.7472×10 <sup>-3</sup>	1.2515×10 <sup>-3</sup>	0.6336×10 <sup>-3</sup>	0.59597×10 <sup>-3</sup>		
τρ	1.785337	0.34595	0.099651	0.014214	2.298151×10 <sup>-3</sup>		

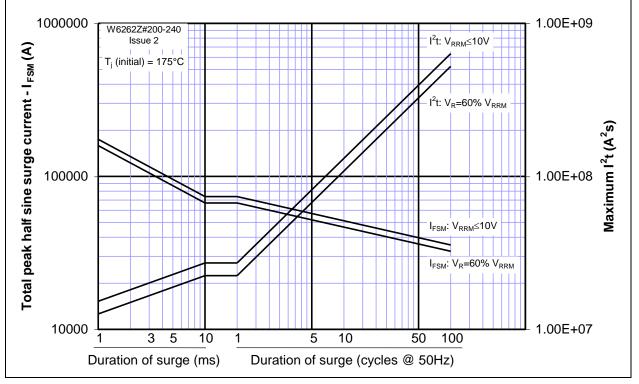


### <u>Curves</u>











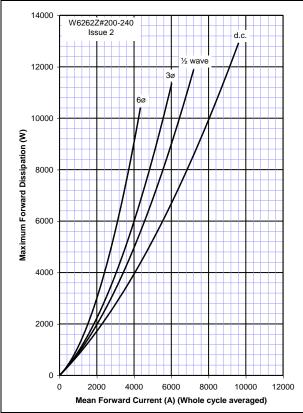


Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

Figure 5 – Forward current vs. Heatsink temperature - Double Side Cooled

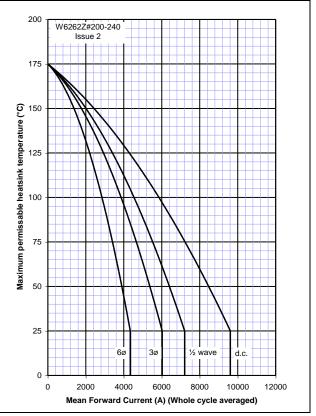
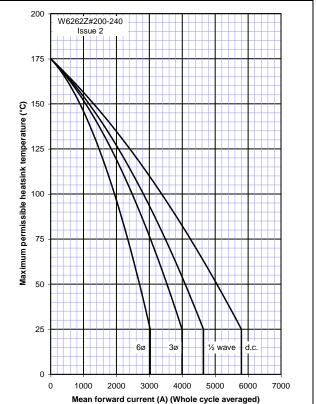
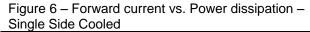
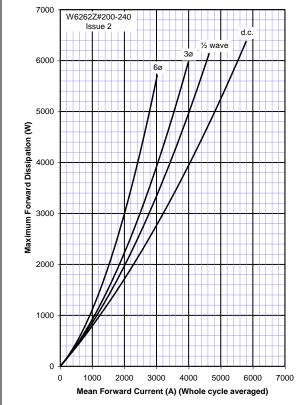


Figure 7 – Forward current vs. Heatsink temperature – Single Side Cooled









#### **Outline Drawing & Ordering Information**

